Onsemi

High-Voltage - High Power Transistors

MJE4343 (NPN), **MJE4353** (PNP)

... designed for use in high power audio amplifier applications and high voltage switching regulator circuits.

Features

• High Collector-Emitter Sustaining Voltage -

NPN PNP

- $V_{CEO(sus)} = 160 \text{ Vdc} \text{MJE4343} \text{ MJE4353}$
- High DC Current Gain @ $I_C = 8.0$ Adc $h_{FE} = 35$ (Typ)
- Low Collector-Emitter Saturation Voltage -

 $V_{CE(sat)} = 2.0 \text{ Vdc} (Max) @ I_C$

= 8.0 Adc

• These are Pb-Free Devices

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	160	Vdc
Collector-Base Voltage	V _{CB}	160	Vdc
Emitter-Base Voltage	V_{EB}	7.0	Vdc
Collector Current – Continuous Peak (Note 1)	Ι _C	16 20	Adc
Base Current – Continuous	Ι _Β	5.0	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$	P _D	125	Watts
Operating and Storage Junc- tion Temperature Range	T _J , T _{stg}	-65 to +150	°C

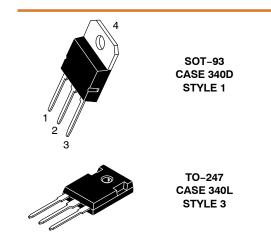
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	1.0	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width \leq 5.0 µs, Duty Cycle \geq 10%.

16 AMPS POWER TRANSISTORS COMPLEMENTARY SILICON **160 VOLTS**

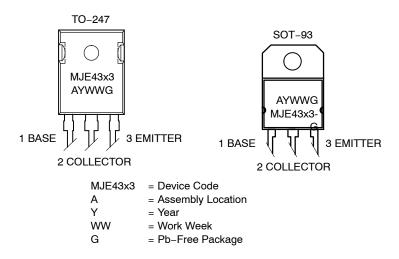


NOTE: Effective June 2012 this device will be available only in the TO-247 package. Reference FPCN# 16827.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MARKING DIAGRAMS



ORDERING INFORMATION

Device Order Number	Package Type	Shipping
MJE4343G	SOT-93 (Pb-Free)	30 Units / Rail
MJE4353G	SOT-93 (Pb-Free)	30 Units / Rail
MJE4343G	TO-247 (Pb-Free)	30 Units / Rail
MJE4353G	TO-247 (Pb-Free)	30 Units / Rail

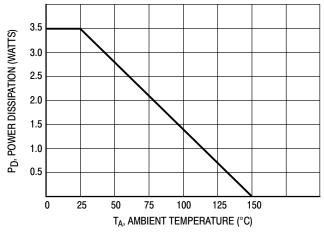


Figure 1. Power Derating Reference: Ambient Temperature

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 2) $(I_C = 200 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	160	-	Vdc
Collector-Emitter Cutoff Current $(V_{CE} = 80 \text{ Vdc}, I_B = 0)$	I _{CEO}	-	750	μAdc
$ Collector-Emitter Cutoff Current \\ (V_{CE} = Rated V_{CB}, V_{EB(off)} = 1.5 Vdc) \\ (V_{CE} = Rated V_{CB}, V_{EB(off)} = 1.5 Vdc, T_C = 150^{\circ}C) $	I _{CEX}		1.0 5.0	mAdc
Collector-Base Cutoff Current $(V_{CB} = Rated V_{CB}, I_E = 0)$	I _{CBO}	-	750	μAdc
Emitter-Base Cutoff Current $(V_{BE} = 7.0 \text{ Vdc}, I_{C} = 0)$	I _{EBO}	-	1.0	mAdc
ON CHARACTERISTICS (Note 2)				
DC Current Gain ($I_C = 8.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 16 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$)	h _{FE}	15 8.0	35 (Typ) 15 (Typ)	-
Collector-Emitter Saturation Voltage ($I_C = 8.0 \text{ Adc}, I_B = 800 \text{ mA}$) ($I_C = 16 \text{ Adc}, I_B = 2.0 \text{ Adc}$)	V _{CE(sat)}		2.0 3.5	Vdc
Base–Emitter Saturation Voltage ($I_C = 16$ Adc, $I_B = 2.0$ Adc)	V _{BE(sat)}	_	3.9	Vdc
Base–Emitter On Voltage ($I_C = 16 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$)	V _{BE(on)}	-	3.9	Vdc
DYNAMIC CHARACTERISTICS	-			
Current–Gain – Bandwidth Product (Note 3) ($I_C = 1.0$ Adc, $V_{CE} = 20$ Vdc, $f_{test} = 0.5$ MHz)	f _T	1.0	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	C _{ob}	Ι	800	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics for the listed test conditions. 2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \geq 2.0%. 3. $f_T = |h_{fe}| \cdot f_{test}$.

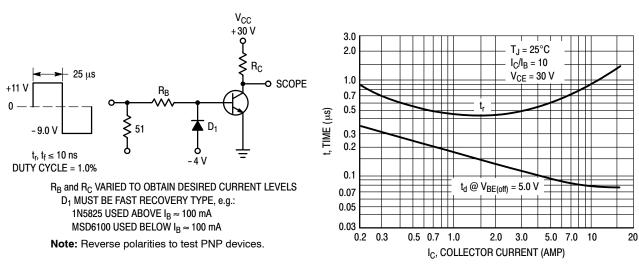
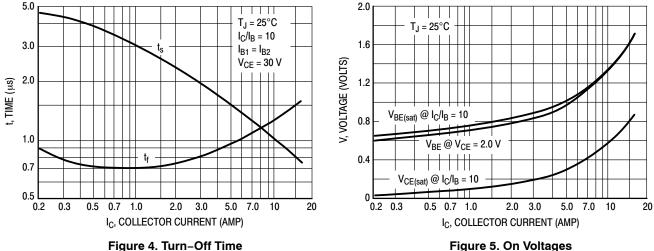




Figure 3. Typical Turn-On Time



TYPICAL CHARACTERISTICS

Figure 5. On Voltages

DC CURRENT GAIN

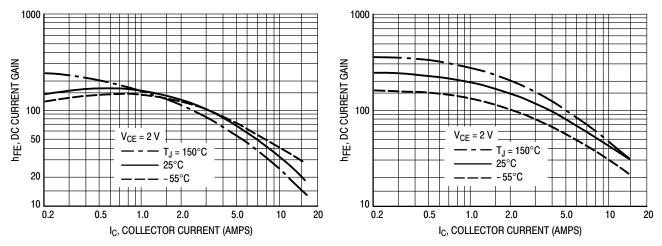
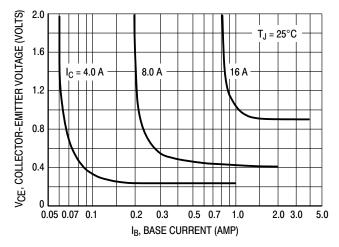


Figure 6. MJE4340 Series (NPN)

Figure 7. MJE4350 Series (PNP)





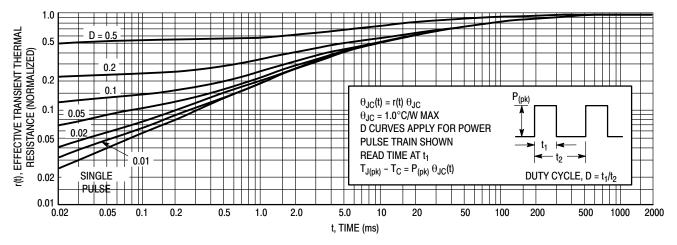


Figure 9. Thermal Response

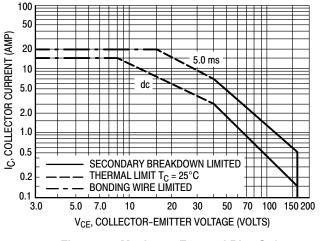


Figure 10. Maximum Forward Bias Safe Operating Area

REVERSE BIAS

For inductive loads, high voltage and high current must be sustained simultaneously during turn-off, in most cases, with the base to emitter junction reverse biased. Under these conditions the collector voltage must be held to a safe level at or below a specific value of collector current. This can be accomplished by several means such as active clamping, RC snubbing, load line shaping, etc. The safe level for these devices is specified as Reverse Bias Safe Operating Area and represents the voltage-current conditions during reverse biased turn-off. This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode. Figure 11 gives RBSOA characteristics. There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 10 is based on $T_C = 25^{\circ}C$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when $T_C \ge 25^{\circ}C$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on Figure 10 may be found at any case temperature by using the appropriate curve on Figure 9.

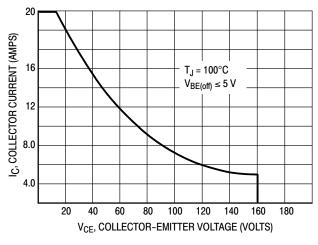
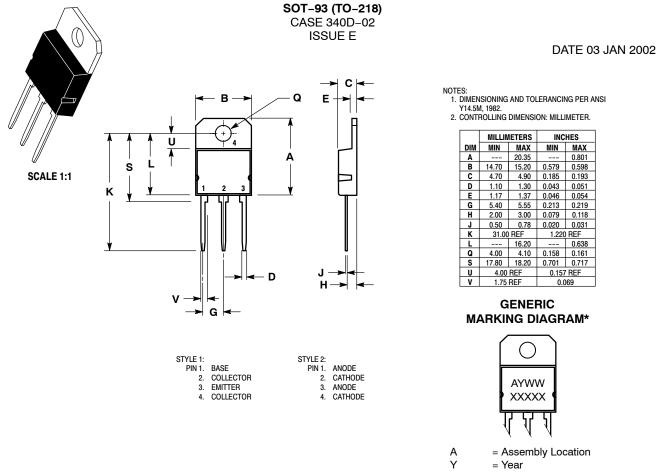


Figure 11. Maximum Reverse Bias Safe Operating Area





- WW = Work Week
- XXXXX = Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98ASB42643B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-93 (TO-218)		PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights of others.

semi

TO-247 CASE 340L ISSUE G G SCALE 1:1 Т В EATING -Ν Α 7 . ർറ ∲Ø0.63 (0.025)@|T|B@ Р Ý 2X F G ·H ЗХ D ♦ 0.25 (0.010) W Y AS

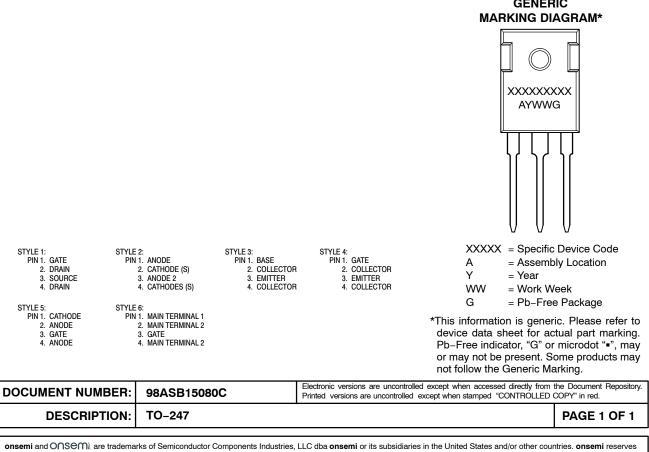
DATE 06 OCT 2021

NOTES

- DIMENSIONING AND TOLERANCING PER ASME 1. Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER

	MILLIMETERS		INCHES	
DIM	MIN.	MAX.	MIN.	MAX.
A	20.32	21.08	0.800	0.830
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
н	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
к	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
Р		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

GENERIC



the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>